University of Mumbai

Examinations Summer 2022

Program: Electronics and Telecommunication Engineering

Curriculum Scheme: Rev2019 Examination: SE Semester III

Course Code: ECC302 and Course Name: Electronic Devices and Circuits

Time: 2 hour 30 minutes Max. Marks: 80

Q1.	Choose the correct option for following questions. All the Questions are compulsory and carry equal marks		
1.	The reverse saturation current of a transistor increases with the increase of temperature at the rate of:		
Option A:	doubles in value for every 1°C increase in temperature		
Option B:	doubles in value for every 25°C increase in temperature		
Option C:	doubles in value for every 10°C increase in temperature		
Option D:	quadruples in value for every 100°C increase in temperature		
2.	Calculate the voltage across R_L. V_i = 9 V, V_Z = 3 V, R=6.8 KOhms, R_L=2.2 KOhms		
Option A:	3.V. 7. 3. 3. 3. 3. 3. 3. 3. 3. 3. 3. 3. 3. 3.		
Option B:	2.2 V		
Option C:			
Option D:	4.4 V 7 V 7 V 8 S S S S S S S S S S S S S S S S S S		
	For a JFET self bias circuit, if the source resistance is increased keeping all other parameters constant, what is the effect on the operating point?		
Option A:	Can't change Source resistance		
Option B:	Remains same		
Option C:	It moves towards ID = IDSS, VGS = 0		
Option D:	It moves towards $ID = 0$, $VGS = VP$		
4	Adding a Resistor between emitter of BJT and Ground terminal of a CE BJT amplifier		
Option A:	Decreases the stability of the amplifier		
Option B:	Improves the stability of the amplifier		
Option C:	Increases the Gain of the amplifier		
Option D:	Has no effect		
5.7	To operate as an amplifier, BJT and MOSFET should operate in& regions respectively		
Option A:	Active and Saturation		

Option B:	Saturation and linear		
Option C:	Cutoff and Linear		
Option D:	Saturation and Cutoff		
	255245000		
6.	For the fixed bias circuit shown, calculate the small signal input impedance, Zi Ohms. Beta=120. R_B=240K Ω , R_C=1.2K Ω , V_CC = 12 V, V_BE = 0.7 V,		
	o Vcc BBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBBB		
	R_B R_C $\downarrow I_C$ ac output signal		
	ac input signal C_1 B_+ V_{CE} V_{CE} V_{CE}		
Ontion A:	1.2 KOhm		
Option A: Option B:	240 Kohm		
Option C:	551 ohm		
Option D:	1 KOhm		
Option D.	1 KOMM		
7.	High cutoff frequency of an amplifier depends on		
Option A:	Output Coupling capacitor		
Option B:	bypass capacitor		
Option C:	Input Coupling capacitor		
Option D:	Parasitic capacitor		
8.	For a direct coupled amplifier, if f_H = 200 KHz then calculate the bandwidth of the amplifier.		
Option A:	1 KHz S S S S S S S S S S S S S S S S S S S		
Option B:	100 KHz		
Option C:	200 KHz		
Option D:	400 KHz		
	If output is measured between two collectors of transistors, then the Differential		
	amplifier with two input signal is said to be configured as		
Option A:	Dual Input Balanced Output		
Option B:	Dual Input Unbalanced Output		
Option C:	Single Input Balanced Output		
Option D:	Single Input Unbalanced Output		
733 C			
10.	Power amplifier directly amplifies		
Option A:	Voltage of signal but not Current		
Option B:	Current of the signal but not Voltage		
Option C:	Power of the signal but not Voltage and Current		
Option D:	Voltage, Current and Power of the signal		

Q2.	Solve any Two Questions out of Three 10 marks each		
A	Determine the following for the network given below Fig. 1 Voltage gain, Current gain, input impedance and output impedance VCC = 16V VCC = 16V Replace Replace Fig. 1 Fig. 1		
В	With neat diagram derive the efficiency of transformer coupled class –A power amplifier? State its uses.		
С	Explain construction and working of n-channel E-MOSFET with output characteristics		

Q3			
A 8 8	Solve any Two	5 marks each	
i, V	For a Class B amplifier providing an 18 V peak signal to a 20 Ω load (Speaker) and a power supply of VCC = 20 V, determine the output power, input power and efficiency.		
	Why should be Rc as large as possible in design of CE amplifier?		
	Explain Zener diode as a voltage regulator.		
STATE BY STATE	Solve any One	10 marks each	
	Let $V_{DD} = 5V$, $V_{TH,1} = 1V$, $k_{n,1}' = 20\mu A/V^2$ and $R = (W/L)_1$ needed for creating $I_{ref} = 1 mA$? What should $I_0 = 7 mA$, $10 mA$ and $15 mA$? Refer Fig. 2		

ii.	For the circuit shown in Fig. 3, the transistor parameter are V_{BE} (on) = 0.7		
	$V, \beta = 200, VA = \infty,$		
	i. Derive the expression for lower cutoff frequency due to input		
	coupling capacitor.		
	ii. Determine lower cut-off frequency and voltage gain		
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	₹2.2K €0.1K 7 € 6.8		
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